

Ground State Properties of Monolayer Doped Graphene

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ABSTRACT

We performed theoretical investigations on self-energy, screening charge density, screened potential and pair distribution function for a doped single layer graphene. Random phase approximation density-density response function and graphene's massless Dirac-fermions concept have been used in our calculations. Local field effects have been included using Hubbard approximation to go beyond random phase approximation. Ultraviolet wave vector cutoff has been used to exclude the effect of vacuum states. Our computed self energy of graphene though displays a behavour similar to that of 2DEG, its magnitude differs drastically from that of 2DEG. Freidel oscillations are seen in computed screened potential and density of screening charge of graphene, which can be seen as a signature of Fermi liquid state in doped graphene. In agreement with experimental results, our computed pair distribution function, as a function of carrier density, suggests that exchange and correlation terms make negligible contribution to compressibility of graphene. Incorporation of LFC reduces the magnitude of self energy, screening charge density and screened potential.

Keywords: Screening Charge Density; Self Energy; Compressibility; Screened Potential

1. Introduction

Graphene has developed into one of the currently most active research in nano-scale physics and can be considered as the building block of many carbon allotropes with vast potential for applications in future technology. Monolayer Graphene (MLG) system has properties of chiral Dirac gas which leads to some important consequences for transport behavior. Graphene's unique properties arise from the collective behavior of electrons. The interaction between electrons and the honeycomb lattice causes electrons to behave as if they have absolutely no mass. The spectrum of Fermions near intersection points is conical and they obey charge conjugation symmetry. Because of the linear energy dispersion, conduction electrons in graphene are governed by Dirac equation which describes relativistic Fermions.

Knowledge of ground state properties of a system is essential in understanding its basic physics and to make use of it for device making. Single-particle spectral function, associated mean free paths, quasiparticle properties, such as inelastic quasiparticle lifetimes quasiparticle decay, renormalization factor, and renormalization velocity can be studied by knowing electron self-energy [1,2]. Self-energy can also be used to obtain ARPES spectra which have been reported by a host of authors for graphene [3-

5]. When a positive charge is placed in an electron gas, the electrons gather around the charge tries to compensate for the electrostatic potential it has induced. The phenomenon is known as screening and it is one of the simplest and most important manifestations of electronelectron interaction [6]. Because of reduced dimensionality and especially because of the semi-metallic nature of graphene's π -electron bands, the problem of screening of charged impurities remains open. In this context, various authors have reported calculations on screening, few of which include scattering treatment of Coulomb impurities embedded within the graphene plane [7,8]. Calculations on charged impurity screening in graphene with the use of vacuum polarization has received a huge attention because of its importance for transport properties and a general understanding of the theory of graphene. Static screening determines transport properties through screened Coulomb carrier scattering by charged impurities [9,10]. The property of screening is also of interest for sensor applications of graphene in detecting atoms or molecules, which may be either absorbed on the upper surface of graphene or intercalated in the gap between the graphene substrate. It has been shown that within the RPA approach, screening of external charges by intrinsic graphene at zero temperature is characterized merely by a renormalization of graphene's background dielectric constant due to interband electron transitions [9-13]. The most common feature

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observed in screened potential is Friedel oscillations, which arise because of derivative discontinuity.

In an interacting electron system of uniform density. the inverse electronic compressibility is a fundamental physical quantity that is intimately related to the strength of inter-electron interactions. The compressibility of electron gas provides valuable information about the nature of the interacting ground state, particularly in the strongcoupling regime where (in addition to the exchange energy) Coulomb interaction energy also plays a dominant role. It also provides information about the chemical potential, stability of the system and so on. Change of local electrostatic potential and thereby change in local chemical potential of MLG was measured with the use of scanning single-electron transistor microscopy when the carrier density was modulated [14]. Observed results on local inverse compressibility were found to be quantitatively described by kinetic energy alone with the electron velocity renormalized by 10% - 15%. It has been speculated that the exchange and correlation energy contributions to compressibility either cancel each other out or are negligibly small. It has been argued that in MLG linear energy dispersion and chirality conspire to allow complete cancellation of exchange and correlation contributions just as was observed in the experiment [15]. This motivated us to compute pair distribution function as a function of carrier density, n to study the n-dependence of compressibility of graphene.

Many-body effects in MLG with zero gap and doping at zero temperature have been the subject of great interests [10,11]. Aim of this paper is to study the ground state properties of doped MLG with the use of modified RPA density-density response function and a wave vector cutoff method, at zero temperature. We have numerically calculated self energy, density of screening charge, screened potential, pair distribution function of doped graphene, using static polarization function with and without local field corrections (LFC). To best of our knowledge these properties have not yet been reported using wave vector cut-off method, which is essential to exclude the contributions from vacuum states. This is in continuation with our earlier work on static and dynamic structure factor of undoped and doped graphene and pair correlation function [16]. The RPA polarization function for low energy excitation involves graphene's π -electron energy bands that have linear energy dispersion. We have calculated Screening charge density for different values of coupling constant and carrier density. Friedel oscillations are observed in the case of screening charge density and screened potential, which can be used to gain insight into microscopic range of disorder. The computed self energy is found to be greater than that for 2D electron gas. We computed pair distribution function as a function of carrier density n to study the n-dependence of compressibility

of graphene. The RPA is a many body theoretical method by which quantitative predictions beyond the Hartree-Fock model can be made. And, though it is very successful in describing many properties nevertheless it has its shortcoming, one of which is that it misses to accommodate the local field effects due to electronic exchange and correlation. The electron-electron correlation and exchange effect beyond the RPA is taken into account by incorporating a term containing the local field corrections in the effective potential. The paper is organized as follows: Formalism is presented in Section 2, numerical results are discussed in Section 3 and the work is concluded in Section 4.

2. Essential Formalism

For a 2D system, self-energy, $E^{sl}(k)$, density of screening charge, $n_s(r)$ and Screened potential, $V_{SCR}(r)$ can be given, respectively, by the following Equation [17];

$$E^{sl}\left(k\right) = 2\int_{0}^{k_{f}} \int_{0}^{2\pi} \frac{1}{4\pi^{2}} \frac{V^{0}\left(\left|\mathbf{k} - \mathbf{k}'\right|\right)}{\varepsilon\left(\left|\mathbf{k} - \mathbf{k}'\right|\right)} k' dk' d\theta \qquad (1)$$

$$n_s(r) = \frac{Ze}{4\pi^2} \int_0^\infty \int_0^{2\pi} e^{iq \cdot r} \left[1 - \frac{1}{\varepsilon(q)} \right] q dq d\theta \qquad (2)$$

$$V_{SCR}(r) = \frac{Ze}{4\pi^2} \int_0^\infty \int_0^{2\pi} e^{iq \cdot r} \left[\frac{V^0(q)}{\varepsilon(q)} \right] q dq d\theta \qquad (3)$$

The static dielectric function $\varepsilon(q)$ is defined as;

$$\varepsilon(q) = 1 + V^{0}(q)\chi^{0}(q) \tag{4}$$

 $V^{0}(q) = 2\pi e^{2}/\kappa q$ is the Fourier transform of 2D bare Coulomb interaction potential, κ is the background dielectric constant and k_f is Fermi momentum. q is replaced by $|\mathbf{k} - \mathbf{k}'|$, in obtaining Equation (1). $\chi^{0}(q)$ is the static polarization function, which for graphene is given by [10]:

$$\chi^{0}(q) = D_{0} \begin{cases} 1 - \frac{\pi q}{8k_{f}} + \frac{\pi q}{8k_{f}}; \\ \text{when } q \leq 2k_{f} \\ 1 - \frac{1}{2}\sqrt{1 - \frac{4k_{f}^{2}}{q^{2}}} - \frac{q}{4k_{f}}\sin^{-1}\frac{2k_{f}}{q} + \frac{\pi q}{8k_{f}}; \\ \text{when } q > 2k_{f} \end{cases}$$
(5)

where, $D_0 = (g_s g_v n/\pi)^{\frac{1}{2}}/\gamma$ is the density of states at Fermi energy, g_s and g_v are the spin and valley degeneracy, and γ is the band parameter. The charge carriers in graphene behave like massless chiral Dirac Fermions. The low energy quasiparticle dynamics of the noninteracting electrons on the hexagonal graphene sheet close to the Fermi energy is described by the spin-independent mass less Dirac-Weyl Hamiltonian, $\mathcal{H} = \hbar v_F \sigma \cdot k$, where

 $\sigma = (\sigma^x, \sigma^y)$ denote the two Pauli matrices that act on the graphene's pseudo spin degrees of freedom and k is 2D wave-vector measured from the two-degenerate K and K' points. This Hamiltonian leads to the linear energy dispersion relation $\epsilon = s\hbar v_E |k'|$, where $s = \pm 1$ indicate the conduction (+1) and valence band (-1), v_E is the Fermi velocity, which is density independent and about 300 times smaller than velocity of light in vacuum. Integration over entire q-range (0 to ∞) in Equations (2) and (3) gives unphysical results because the polarizability response function of graphene includes the vacuum fluctuations of the infinite sea of negative particles. The nonzero vacuum weight is a relativistic signature of graphene and it is a conesquence of particle-antiparticle pair creation or the Dirac sea. To overcome this we introduce an ultraviolet wave vector cut off k_a , which becomes necessary to make quantitative predictions for the peculiar case of graphene [18]. The upper limit of q-integration is therefore taken k_a in place of ∞ in Equations (2) and (3). k_a is determined in a way so as to keep the number of states in Brillouin zone fixed, that is, $\pi k_a^2 = (2\pi)^2/A_0$, in which $A_0 = 3\sqrt{3}a_0^2/2$ is the area of the unit cell in the honeycomb lattice and $a_0 = 1.42A^0$ is the carbon-carbon distance [16].

We have computed pair distribution function as a function of n to study the n-dependence of compressibility of graphene. The compressibility can be defined by

 $k^{-1} = \partial^2 \varepsilon / \partial n^2$, where energy per particle functional, ε can be expressed in terms of kinetic energy per particle, t_0 , Coulomb potential, V_{coul} , pair correlation function, g(r) as follows [19];

$$\frac{\partial^{2} \varepsilon}{\partial n^{2}} = \frac{\partial^{2} t_{0}}{\partial n^{2}} + 2 \int dr V_{coul} \frac{\delta g(r)}{\delta n} + n \int dr V_{coul} \frac{\left(\frac{\delta g(r)}{\delta n}\right)}{\delta n}$$
(7)

g(r,z) for graphene can be given by:

$$g(r,z) = 1 + \frac{1}{2n\pi} \int_{0}^{k_{a}} q J_{0}(qr) \left[S(q,z) - 1 \right] dq$$
 (8)

where $n = z \times 10^{14} \text{ cm}^{-2}$.

S(q,z) is static structure factor, which has been defined elsewhere for graphene [16]. To go beyond RPA in calculating $E^{sl}(\mathbf{k})$, $n_s(r)$ and $V_{SCR}(r)$, bare coulomb interaction is replaced by effective electron-electron interaction, $V^{eff}(q)$ that includes local field effects can be given by [17];

$$V^{eff}(q) = V^{0}(q) \left[1 - G(q)\right]$$
(9)

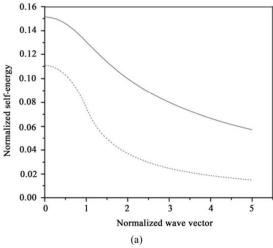
where G(q) is the static local field correction (LFC) term, which in simplest manner can be defined within Hubbard approximation (HA) to give

$$G(q) = V^{0}(q')/V^{0}(q)$$
, with $q' = \sqrt{q^{2} + k_{f}^{2}}$.

3. Results and Discussions

We computed Equations (1), (2), (3) and (8) numerically for MLG in terms of dimensional less quantities $x = q/k_f$ and $y = \omega/E_f$ and the dimensionless coupling constant $\alpha = g_s g_v e^2 \kappa \hbar/v_f$, where κ varies between 1 and 2 for SiC and SiO₂ substrate. The coupling constant is a ratio of coulomb energy to kinetic energy and it is independent of the electronic density. It depends only on material properties and environmental conditions and it is the measure of the strength of the Columbic attraction. α is also used to characterize the ratio of coulomb interaction and band energy scales in graphene.

The self-energy is the central quantity for determining the many Fermi liquid parameters. Our computed E^{st}/e^2k_f from Equation (1) is plotted as a function of x in **Figure 1(a)** without LFC and in **Figure 1(b)** with the inclusion



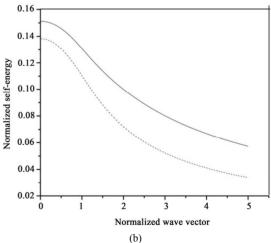


Figure 1. (a) Normalized screened self energy, E^{sl}/e^2k_f is plotted against normalized wave vector k/k_f Solid Curve displays Self energy of graphene while dashed curve is for 2DEG, without LFC; (b) Normalized screened self energy, E^{sl}/e^2k_f as a function of k/k_f without LFC (solid line curve) with LFC (dashed line curve).

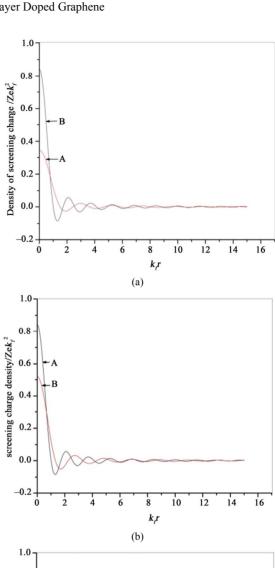
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pare it with that of doped MLG. As is seen from **Figure 1(a)**, behavior of computed E^{sl}/e^2k_f of MLG with x is very similar to that of 2DEG. However, magnitude of E^{sl}/e^2k_f of doped MLG is greater than of that of 2DEG. The difference in magnitude of E^{sl} of MLG and of 2DEG is because of different values of intrinsic parameters of two systems, which enter into self-energy through static dielectric function that can be described by

of LFC. We also computed self-energy of 2DEG to com-

 $\varepsilon(q) = (1 + \beta/q)$ for both MLG and 2DEG. Where β is equal to $4m^*e^2/\kappa\hbar^2k_f$ which depends on n in case of 2DEG, while for graphene it is independent of n. For computing E^{sl} of 2DEG, we have used $m^* = 0.067~m_e$ and $\kappa = 13$. Further to see the effect of LFC on self-energy, we computed E^{sl}/e^2k_f including LFC within HA for doped MLG. As is seen from **Figure 1(b)**; 1) magnitude of self-energy reduces marginally; and 2) downward slope of E^{sl} verses x enhances, especially for x > 1, on inclusion of LFC. This suggests that local fields does not play very important role in determination of self-energy in a doped MLG.

Our computed $n_s(r)$ is plotted as a function of $k_s r$ in Figure 2(a) for two values of α (=2 & 4) at fix value of n and in **Figure 2(b)** for two values of n (n = 4.77 $\times 10^{14} \text{ cm}^{-2} \& 8.04 \times 10^{14} \text{ cm}^{-2}$) for $\alpha = 4$. Computed $n_s(r)$ is finite for r tending to zero and it exhibits oscillations, which eventually decays for larger values of r. These oscillations are known as Friedel oscillations and are the result of the non-analyticity which occurs because of the discontinuity in second derivative, the first being continuous [11,20]. As is displayed in Figure 2(a), on increasing the value of α for fixed value of n; 1) $n_{\rm s}(r)$ substantially enhances for lower values of r (close to $r \to 0$; and 2) Friedel oscillations becomes more pronounced. The behaviour of our computed $n_s(r)$ is very similar to that observed in a Fermi liquid where many body effects influence the amplitude of oscillations which are characterized by power law decay and depend on the strength of the interactions [11]. **Figure 2(b)**, shows that on increasing carrier density at fixed value of α , magnitude of $n_s(r)$ reduces specially for $k_f r$ close to zero and the amplitude of Friedel oscillations decreases. Inclusion of LFC reduces the magnitude of $n_s(r)$ at all rvalues and makes it better behaved for $r \to 0$, as is seen from Figure 2(c). Our computed screened potential with the use of Equation (3) is plotted in **Figure 3**. Friedel Oscillations are clearly observed in the potential images which are in good agreement with the experimental work conducted on 2D electron gas, using low temperature Scanning tunneling microscope [21]. Inclusion of LFC reduces the magnitude of $V_{SCR}(r)$ too and makes it better behaved as is displayed in Figure 3. Under the RPA approximation, which assumes that the induced charge



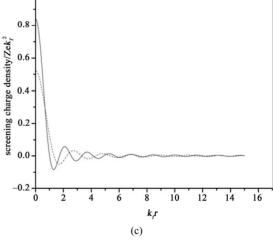


Figure 2. (a) Density of screening charge plotted against k_{fr} for $n=4.77\times 10^{14}~{\rm cm}^{-2}$ at $\alpha=2$ (Curve-A) and for $\alpha=4$ (curve-B); (b) Density of screening charge plotted agains k_{fr} for $\alpha=4$ at $n=8.04\times 10^{14}~{\rm cm}^{-2}$ (curve-B) and $n=4.77\times 10^{14}~{\rm cm}^{-2}$ (curve-A); (c) Screening charge density with LFC (dashed line) and without LFC (solid line) for $\alpha=4$ at $n=8.04\times 10^{14}~{\rm cm}^{-2}$.

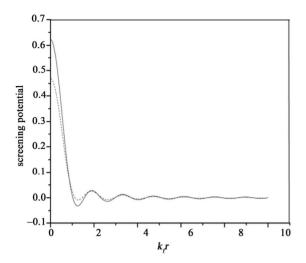


Figure 3. Screened potential $V_{SCR}(r) \rightarrow k_f r$; with LFC (dashed line), without LFC (solid line).

density is proportional to the total potential, the screened potential oscillates spatially. The observation of Friedel oscillations in screened potential and screening charge density can be seen as a signature of Fermi liquid state in graphene [22]. The Friedel oscillations can be used to gain insight into the microscopic nature of disorder. We compared our computed $n_s(r)$ and $V_{SCR}(r)$ of doped MLG with that of 2DEG. It is found that the overall behavior of $n_s(r)$ and $V_{SCR}(r)$ of doped MLG is not very different from that of 2DEG, though the nature of charge carriers in two systems is very different [17]. It therefore can be inferred that the linear energy dispersion and chirality of MLG does not significantly influence gross many particle properties.

The pair distribution function gives the probability that another electron is a distance **r** away from the first [23]. We computed g(r) as a function of carrier density at different α -values. To study the pair distribution function as a function of carrier density we took $n = z \times 10^{14}$ cm⁻² at a fixed $r = 1 \times 10^{-7}$ cm Further for computation we take dimensional less quantity q/q_0 , where $q_0 = 1 \times$ 10⁷ cm⁻¹ Our computed results are displayed in **Figure 4** for different values of α . For all values of α , computed g(r, z) as a function of carrier density saturates at higher values of z, as is exhibited in the **Figure 4**, clearly suggests that the variation of g(r, z) with n is roughly zero over the experimentally observed range of n in doped MLG. Looking at **Figure 4** and Equation (7), we can conclude that exchange and correlation terms make negligible contribution to compressibility in MLG, as has been observed in experimental results on compressibility of MLG [14].

4. Conclusion

In summary, we studied the self energy, density of screen-

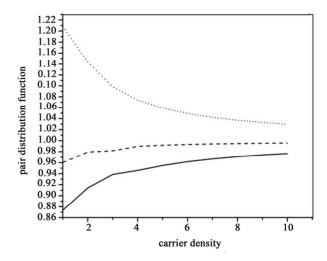


Figure 4. Pair distribution function $g(r,z) \rightarrow z$ for $\alpha = 1$ (soild line), $\alpha = 2$ (dotted line) and $\alpha = 3$ (dashed line).

ing charge and screened potential within and beyond RPA. Local field corrections were incorporated in the Hubbard approximation to go beyond RPA. Ultraviolet cutoff for wave vector integral has been used to exclude the effect of vacuum states in MLG. Self energy, density of screening charge and screened potential of MLG are found to behave similar to that of 2DEG since the dielectric function is almost similar upto $q < 2k_f$. Freidel oscillations have been observed in screened potential and density of screening charge. With increase in the value of α for a fixed value of carrier density, Friedel oscillations enhance, whereas on keeping α fixed and increasing carrier density reduces the amplitude of the oscillations. The observation of Friedel oscillations in screened potential and screening charge density can be seen as a signature of Fermi liquid state in graphene. Pair distribution function is calculated as a function of carrier density suggests that exchange and correlation terms make negligible contribution to compressibility of graphene. Incorporation of LFC reduces the magnitude of self energy, screening charge density and screened potential.

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